ASSP for Mobile Telephone

VCO (800 to 2000 MHz)

VC-24 Series

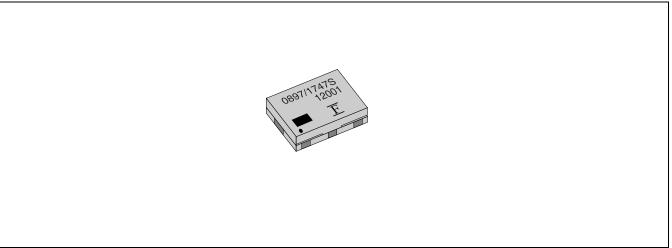
DESCRIPTION

With excellent C/N characteristics and low current consumption, this VCO series is suitable for use with GSM and DCS and is ideal to miniaturize dual-band mode products. The VC-24 series can be used in any frequency band in the 800 MHz to 2000 MHz range. The device utilizes FUJITSU MEDIA DEVICE's high-frequency design technology, high-density mounting technology, and frequency adjustment technology to provide a high level of reliability in addition to high performance and small size.

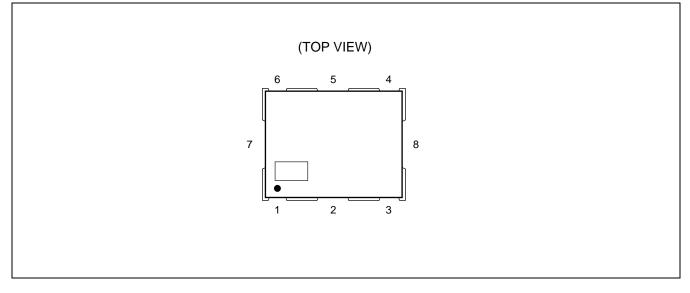
FEATURES

- Superior noise characteristics (C/N, S/N)
- Frequency switching type
- · High level of stability in response to ambient temperature and load variations
- FUJITSU MEDIA DEVICE's proprietary fabrication process provides a uniform central frequency distribution
- Small size, light-weight, slim-package : $9.3 \times 7.2 \times 2.0$ mm (Max.)
- SMD-type taping specifications suitable for automatic mounting and reflow soldering

PACKAGE



■ PIN ASSIGNMENT



■ PIN DESCRIPTION

Pin No.	Symbol	Description				
1	Vt	Control voltage				
2	GND	GND				
3	Vcc	Power Supply Voltage				
4	OUT	Output				
5	GND	GND				
6	Vsw	Band select				
7	GND	GND				
8	GND	GND				

■ PRODUCT LINEUP (STANDARD MODELS)

System		Center Frequency (MHz)	Band Width (MHz)	Power Supply Voltage (V)	Part Number
	Tv	897	±17.5	2.8 ± 0.1	VC-2R8A24-0897/1747S
	Тх	1747	±37.5	2.0 ± 0.1	VG-2R0A24-0097/17473
GSM/DCS		1167	±17.5	2.8 ± 0.1	VC-2R8A24-1167/1617
03101/003	Rx	1617	±40	2.0 ± 0.1	VG-2R0A24-1107/1017
	Rx	1202	±40	2.8 ± 0.1	VC-2R8A24-1202/1559P
	ΓX	1559	±39	2.0 ± 0.1	VG-2R0A24-1202/1999P

ELECTRICAL CHARACTERISTICS

1. For GSM/DCS (Tx) (Part number : VC-2R8A24-0897/1747S)

Absolute Maximum Ratings

Parameter	Symbol	Ra	Rating		
Faidilielei	Symbol	Min.	Max.	Unit	
Input DC voltage	Vcc		+3.0	V	
Control voltage	Vt		+3.0	V	
SW voltage	Vsw		+3.0	V	
Operating temperature	Та	-10	+75	°C	
Storage temperature	Tstg	-30	+85	°C	
Storage humidity	Hstg	5	95	%	

WARNING: VCO can be permanently damaged by application of stress (voltage, temperature, humidity, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

• Band Selection Mode

Band Width	Selection Mode	Vsw (V)		Center Frequency	Current Consumption	
Balla Width	Selection would	Min.	Max.	(MHz)	(mA) Typ.	
GSM	Band1	0.0	0.1	897	0.0	
DCS	Band2	2.7	2.8	1747	0.5	

• Electrical Characteristics

Band1

 $(Ta = -10^{\circ}C \text{ to } +75^{\circ}C)$

Devementer	Symbol Conditions			11:0:4		
Parameter S	Symbol			Тур.	Max.	Unit
Current consumption	Icc	Vcc = 2.8 V, Vt = 1.35 V			38.0	mA
SW current	Isw	$V_{CC} = 2.8 \text{ V}, \text{ Vt} = 1.35 \text{ V}, \text{ Vsw} = 0 \text{ V}$		—	0.1	mA
Frequency	fmin	Vcc = 2.8 V, Vt = 0.5 V		—	880.0	MHz
Frequency	fmax	Vcc = 2.8 V, Vt = 2.2 V	915.0	—		MHz
Control voltage sensitivity	Svt	(fmax – fmin) /1.7	32.0	38.0	44.0	MHz/V
Oscillator output	Po	$V_{CC} = 2.8 \text{ V}, \text{ Vt} = 1.35 \text{ V}$	5.5	8.5	11.5	dBm
	C/N	Vcc = 2.8 V, Vt = 1.35 V, Offset = 10 kHz, BW = 1 Hz			-93.0	dBc/Hz
C/N		Vcc = 2.8 V, Vt = 1.35 V, Offset = 400 kHz, BW = 1 Hz			-123.0	dBc/Hz
C/N	C/N	Vcc = 2.8 V, Vt = 1.35 V, Offset = 10 MHz, BW = 1 Hz			-153.0	dBc/Hz
		Vcc = 2.8 V, Vt = 1.35 V, Offset = 20 MHz, BW = 1 Hz	_		-162.0	dBc/Hz
Higher harmonics	Hs	$V_{CC} = 2.8 V, Vt = 1.35 V,$ Up to 3rd		_	-10.0	dBc
Power supply variation	Push	$V_{CC} = 2.8 \text{ V} \pm 0.1 \text{ V}, \text{ Vt} = 1.35 \text{ V}$	_		±1000	kHz
Load variation	Pull	V _{CC} = 2.8 V , Vt = 1.35 V, VSWR = 2, All phases			±2000	kHz
Temperature drift	Td	$V_{CC} = 2.8 \text{ V}, \text{ Vt} = 1.35 \text{ V}$			±3000	kHz

Band2

Danuz					(Ta = −10°C	to +75°C)	
Paramatar	Symbol	Conditions		Value			
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Current consumption	Icc	Vcc = 2.8 V, Vt = 1.35 V		_	38.0	mA	
SW current	lsw	$V_{CC} = 2.8 V, V_{t} = 1.35 V, V_{SW} = 2.8 V$			1.0	mA	
Frequency	fmin	$V_{CC} = 2.8 \text{ V}, \text{ Vt} = 0.5 \text{ V}$			1710.0	MHz	
Frequency	fmax	$V_{CC} = 2.8 V, Vt = 2.2 V$	1785.0			MHz	
Control voltage sensitivity	Svt	(fmax – fmin) /1.7	57.0	67.0	77.0	MHz/V	
Oscillator output	Po	Vcc = 2.8 V, Vt = 1.35 V	4.5	7.5	10.5	dBm	
	C/N	Vcc = 2.8 V, Vt = 1.35 V, Offset = 10 kHz, BW = 1 Hz			-90.0	dBc/Hz	
C/N		Vcc = 2.8 V, Vt = 1.35 V, Offset = 400 kHz, BW = 1 Hz			-120.0	dBc/Hz	
C/N		Vcc = 2.8 V, Vt = 1.35 V, Offset = 10 MHz, BW = 1 Hz			-150.0	dBc/Hz	
		Vcc = 2.8 V, Vt = 1.35 V, Offset = 20 MHz, BW = 1 Hz			-157.0	dBc/Hz	
Higher harmonics	Hs	$V_{CC} = 2.8 V, Vt = 1.35 V,$ Up to 3rd	_	_	-10.0	dBc	
Power supply variation	Push	$V_{CC} = 2.8 \text{ V} \pm 0.1 \text{ V}, \text{ Vt} = 1.35 \text{ V}$		_	±2000	kHz	
Load variation	Pull	Vcc = 2.8 V , Vt = 1.35 V, VSWR = 2, All phases			±4000	kHz	
Temperature drift	Td	Vcc = 2.8 V, Vt = 1.35 V			±5000	kHz	

2. For GSM/DCS (Rx) (Part number : VC-2R8A24-1167/1617)

Absolute Maximum Ratings

Parameter	Symbol	Ra	Unit	
Falameter	Symbol	Min.	Max.	Onit
Input DC voltage	Vcc		+3.0	V
Control voltage	Vt	—	+3.0	V
SW voltage	Vsw	—	+3.0	V
Operating temperature	Та	-10	+75	°C
Storage temperature	Tstg	-30	+85	°C
Storage humidity	Hstg	5	95	%

WARNING: VCO can be permanently damaged by application of stress (voltage, temperature, humidity, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

• Band Selection Mode

Band Width	Selection Mode	Vsw (V)		Center Frequency	Current Consumption	
	Selection would	Min.	Max.	(MHz)	(mA) Typ.	
GSM	Band1	0.0	0.1	1167	0.0	
DCS	Band2	2.7	2.8	1617	0.5	

• Electrical Characteristics

Band1

 $(Ta = -10^{\circ}C \text{ to } +75^{\circ}C)$

Devenueter	Sym-	Conditions		Value		Unit
Parameter	bol	Conditions	Min.	Тур.	Max.	Unit
Current consumption	lcc	$V_{CC} = 2.8 \text{ V}, \text{ Vt} = 1.35 \text{ V}$			10.0	mA
SW current	lsw	$V_{CC} = 2.8 \text{ V}, \text{ Vt} = 1.35 \text{ V}, \text{ Vsw} = 0 \text{ V}$	_		0.1	mA
Frequency	fmin	Vcc = 2.8 V, Vt = 0.5 V	—		1150.0	MHz
Frequency	fmax	Vcc = 2.8 V, Vt = 2.2 V	1185.0	_	—	MHz
Control voltage sensitivity	Svt	(fmax – fmin) /1.7	29.0	36.0	43.0	MHz/V
Oscillator output	Po	$V_{CC} = 2.8 \text{ V}, \text{ Vt} = 1.35 \text{ V}$	-6.0	-2.0	2.0	dBm
	C/N	Vcc = 2.8 V, Vt = 1.35 V, Offset = 10 kHz, BW = 1 Hz			-85.0	dBc/Hz
C/N		Vcc = 2.8 V, Vt = 1.35 V, Offset = 600 kHz, BW = 1 Hz			-123.0	dBc/Hz
C/N		Vcc = 2.8 V, Vt = 1.35 V, Offset = 1.6 MHz, BW = 1 Hz			-133.0	dBc/Hz
		Vcc = 2.8 V, Vt = 1.35 V, Offset = 3 MHz, BW = 1 Hz			-142.0	dBc/Hz
Higher harmonics	Hs	Vcc = 2.8 V, Vt = 1.35 V			-10.0	dBc
Power supply variation	Push	$V_{CC} = 2.8 \text{ V} \pm 0.1 \text{ V}, \text{ Vt} = 1.35 \text{ V}$			±1000	kHz
Load variation	Pull	Vcc = 2.8 V , Vt = 1.35 V, VSWR = 2, All phases			±1500	kHz
Temperature drift	Td	Vcc = 2.8 V, Vt = 1.35 V			±3000	kHz

Band2

 $(Ta = -10^{\circ}C \text{ to } +75^{\circ}C)$

Parameter	Symbol Conditions			Unit		
		Conditions	Min.	Тур.	Max.	Unit
Current consumption	Icc	Vcc = 2.8 V, Vt = 1.35 V	—	—	10.0	mA
SW current	Isw	$V_{CC} = 2.8 V, Vt = 1.35 V, V_{SW} = 2.8 V$		—	1.0	mA
Frequency	fmin	Vcc = 2.8 V, Vt = 0.5 V	—	—	1577.5	MHz
Frequency	fmax	$V_{CC} = 2.8 V, Vt = 2.2 V$	1657.5	—	—	MHz
Control voltage sensitivity	Svt	(fmax – fmin) /1.7	56.0	66.0	76.0	MHz/V
Oscillator output	Po	Vcc = 2.8 V, Vt = 1.35 V	-6.0	-2.0	+2.0	dBm
	0.01	Vcc = 2.8 V, Vt = 1.35 V, Offset = 10 kHz, BW = 1 Hz		_	-85.0	dBc/Hz
C/N		Vcc = 2.8 V, Vt = 1.35 V, Offset = 400 kHz, BW = 1 Hz			-123.0	dBc/Hz
C/N	C/N	Vcc = 2.8 V, Vt = 1.35 V, Offset = 10 MHz, BW = 1 Hz			-133.0	dBc/Hz
		Vcc = 2.8 V, Vt = 1.35 V, Offset = 20 MHz, BW = 1 Hz	_		-140.0	dBc/Hz
Higher harmonics	Hs	$V_{CC} = 2.8 V, Vt = 1.35 V,$ Up to 3rd	_		-10.0	dBc
Power supply variation	Push	$V_{CC} = 2.8 \text{ V} \pm 0.1 \text{ V}, \text{ Vt} = 1.35 \text{ V}$		_	±1500	kHz
Load variation	Pull	$V_{CC} = 2.8 \text{ V}$, $Vt = 1.35 \text{ V}$, VSWR = 2, All phases		_	±2000	kHz
Temperature drift	Td	Vcc = 2.8 V, Vt = 1.35 V			±5000	kHz

3. For GSM/DCS (Rx) (Part number : VC-2R8A24-1202/1559P)

Absolute Maximum Ratings

Parameter	Symbol	Ra	Unit	
Falameter	Symbol	Min.	Max.	Onit
Input DC voltage	Vcc	0.0	+3.0	V
Control voltage	Vt	0.0	+2.5	V
SW voltage	Vsw	0.0	+3.0	V
Operating temperature	Та	-20	+75	°C
Storage temperature	Tstg	-35	+85	°C
Storage humidity	Hstg	5	95	%

WARNING: VCO can be permanently damaged by application of stress (voltage, temperature, humidity, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

• Band Selection Mode

Band Width	Selection Mode	Vsw (V)		Center Frequency	Current Consumption	
	Selection Mode	Min.	Max.	(MHz)	(mA) Typ.	
GSM	Band1	0.0	0.3	1202	0.0	
DCS	Band2	2.5	2.8	1559	0.4	

• Electrical Characteristics

Band1

 $(Ta = -20^{\circ}C \text{ to } +75^{\circ}C)$

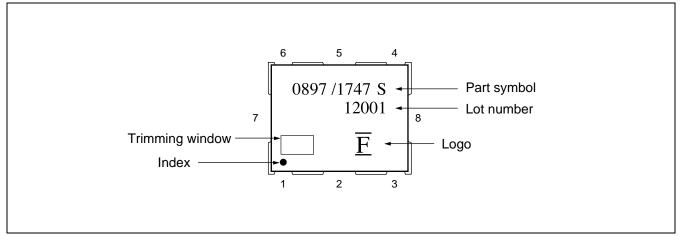
Parameter	Sym- bol	Conditions	Value			Unit
			Min.	Тур.	Max.	Unit
Current consumption	lcc	Vcc = 2.8 V, Vt = 1.5 V	_	—	9.0	mA
SW current	sw	Vcc = 2.8 V, Vt = 1.5 V, Vsw = 0 V	_		0.1	mA
Frequency	fmin	Vcc = 2.8 V, Vt = 0.8 V			1162.0	MHz
Frequency	fmax	Vcc = 2.8 V, Vt = 2.2 V	1242.0			MHz
Control voltage sensitivity	Svt	(fmax – fmin) /1.4	66.0	76.0	86.0	MHz/V
Oscillator output	Po	Vcc = 2.8 V, Vt = 1.5 V	-5.0	-2.0	1.0	dBm
C/N	C/N	Vcc = 2.8 V, Vt = 1.5 V, Offset = 10 kHz, BW = 1 Hz	85.0			dBc/Hz
		Vcc = 2.8 V, Vt = 1.5 V, Offset = 3000 kHz, BW = 1 Hz	140.0			dBc/Hz
Higher harmonics	Hs	$V_{CC} = 2.8 \text{ V}, \text{ Vt} = 1.5 \text{ V},$ Up to 3rd			-10.0	dBc
Spurious	Sp	Vcc = 2.8 V, Vt = 1.5 V, Offset = 3 MHz (Min.)	_		-87.0	dBc
Power supply variation	Push	$Vcc = 2.8 V \pm 0.1 V$, $Vt = 1.5 V$			±1000	kHz
Load variation	Pull	$V_{CC} = 2.8 \text{ V}, \text{ Vt} = 1.5 \text{ V},$ VSWR = 2, All phases			±2000	kHz

Band2

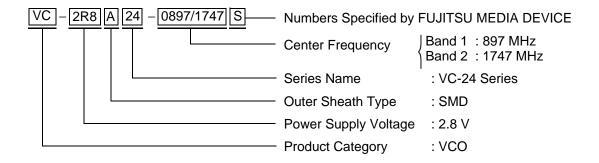
 $(Ta = -20^{\circ}C \text{ to } +75^{\circ}C)$

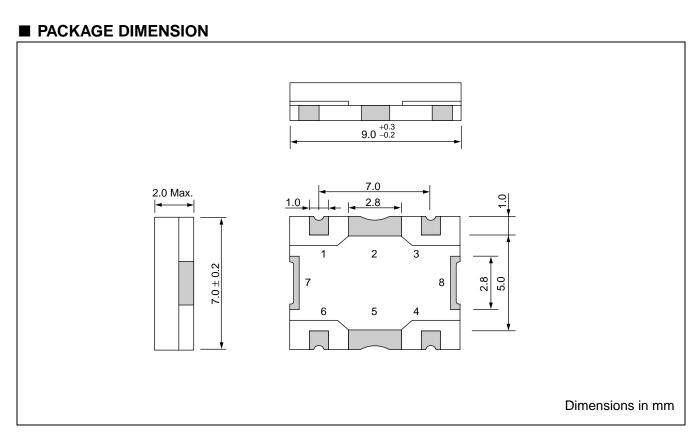
Parameter	Symbol	Conditions	Value			Unit
Farameter			Min.	Тур.	Max.	Unit
Current consumption	Icc	Vcc = 2.8 V, Vt = 1.5 V	—	—	10.5	mA
SW current	Isw	$V_{CC} = 2.8 \text{ V}, \text{ Vt} = 1.5 \text{ V}, \text{ Vsw} = 2.8 \text{ V}$		_	1.0	mA
Frequency	fmin	$V_{CC} = 2.8 V, Vt = 0.8 V$		_	1520.0	MHz
Frequency	fmax	$V_{CC} = 2.8 V, Vt = 2.2 V$	1598.0	_	—	MHz
Control voltage sensitivity	Svt	(fmax – fmin) /1.4	88.0	98.0	108.0	MHz/V
Oscillator output	Po	$V_{CC} = 2.8 V, Vt = 1.5 V$	-6.0	-2.0	2.0	dBm
C/N	C/N	Vcc = 2.8 V, Vt = 1.5 V, Offset = 10 kHz, BW = 1 Hz	85.0			dBc/Hz
		Vcc = 2.8 V, Vt = 1.5 V, Offset = 3000 kHz, BW = 1 Hz	135.0			dBc/Hz
Higher harmonics	Hs	Vcc = 2.8 V, Vt = 1.5 V, 2nd, 3rd			-10.0	dBc
Spurious	S₽	Vcc = 2.8 V, Vt = 1.5 V, Offset = 3 MHz (Min.)	_	_	-82.0	dBc
Power supply variation	Push	$V_{CC} = 2.8 V \pm 0.1 V,$ Vt = 1.5 V			±1000	kHz
Load variation	Pull	$V_{CC} = 2.8 V$, $Vt = 1.5 V$, VSWR = 2, All phases			±2000	kHz

■ MARKING

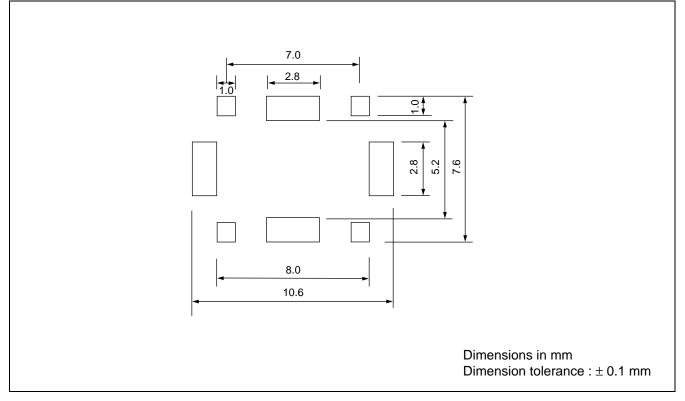


■ PART NUMBER DESIGNATION



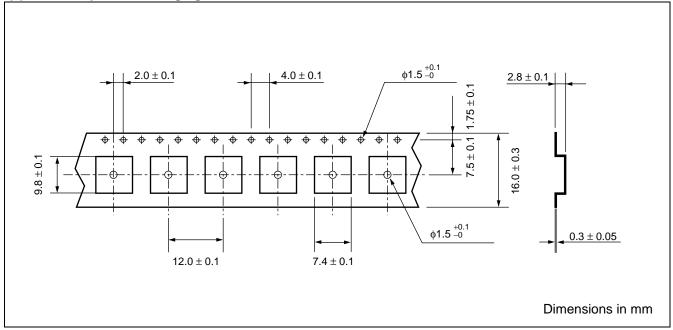


■ RECOMMENDED PATTERN FOR SOLDERING

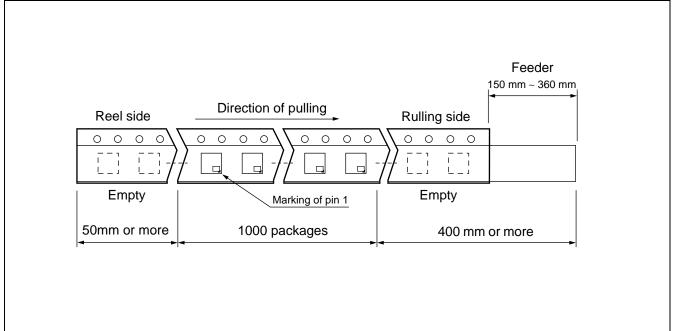


■ TAPING AND PACKAGING

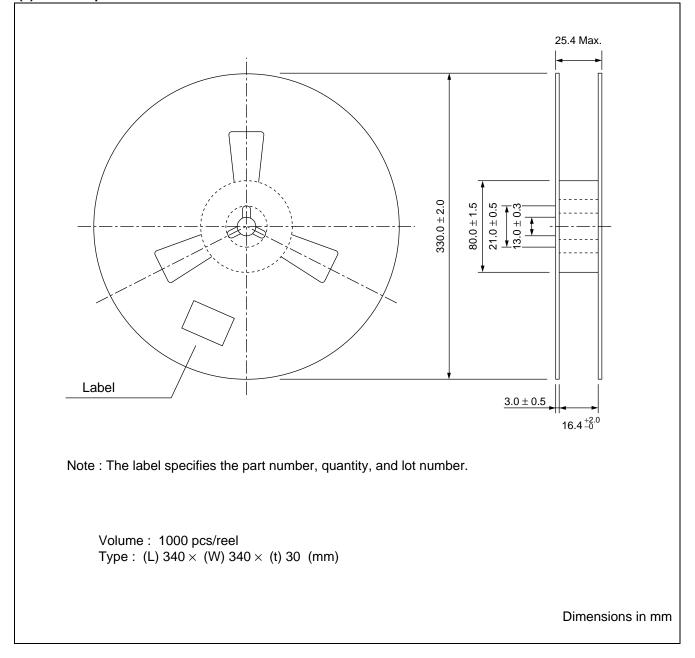
(1) Carrier Tape and Packaging



(2) Taping Layout

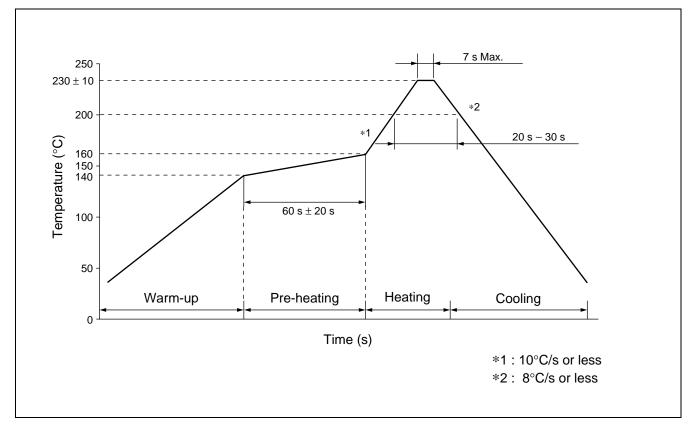


(3) Reel Shape and Dimensions



■ REFLOW MOUNTING CONDITIONS (RECOMMENDED)

- Perform mounting using the temperature profile shown below. To prevent thermal stress to the VCO, ensure gentle temperature gradients and use preheating whenever possible.
- Always consult FUJITSU MEDIA DEVICE beforehand if mounting more than once.
- Never remove a VCO that has already been mounted and attempt to reuse.
- For mounting, use a general-purpose flux suitable for mounting electronic components.



WASHING CONDITIONS

- Washing solution: Use isopropyl alcohol.
- Washing procedure: Immersion or steam cleaning is recommended.
- Washing time: For immersion: Less than 5 minutes at 40°C or less.
 - For steam: Less than 2 minutes at 90°C or less is recommended.

FUJITSU MEDIA DEVICES LIMITED

For further information please contact:

Japan

FUJITSU MEDIA DEVICE LIMITED International SalesMarketing DEPT. Shin-Yokohama Square Bldg.,14F, Shin-yokohama 2-3-12, Kohoku-ku, Yokohama, Kanagawa 222-0033, Japan Tel: +81-45-471-0061 Fax: +81-45-471-0076

http://www.fujitsu.co.jp/hypertext/fmd/English/index.html

North and South America

FUJITSU MICROELECTRONICS, INC. 3545 North First Street, San Jose, CA 95134-1804, U.S.A. Tel: +1-408-922-9000 Fax: +1-408-922-9179

Customer Response Center *Mon. - Fri.: 7 am - 5 pm (PST)* Tel: +1-800-866-8608 Fax: +1-408-922-9179

http://www.fujitsumicro.com/

Europe

FUJITSU MICROELECTRONICS EUROPE GmbH Am Siebenstein 6-10, D-63303 Dreieich-Buchschlag, Germany Tel: +49-6103-690-0 Fax: +49-6103-690-122

http://www.fujitsu-fme.com/

Asia Pacific

FUJITSU MICROELECTRONICS ASIA PTE. LTD. #05-08, 151 Lorong Chuan, New Tech Park, Singapore 556741 Tel: +65-281-0770 Fax: +65-281-0220

http://www.fmap.com.sg/

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